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With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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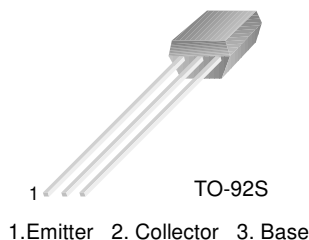
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



KSA1175

Low Frequency Amplifier

- Collector-Base Voltage : $V_{CBO} = -60V$
- Complement to KSC2785



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	-60	V
V_{CEO}	Collector-Emitter Voltage	-50	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current	-150	mA
P_C	Collector Power Dissipation	250	mW
T_J	Junction Temperature	150	$^\circ C$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ C$

Electrical Characteristics $T_a = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C = -100\mu A, I_E = 0$	-60			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -10mA, I_B = 0$	-50			V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E = -10\mu A, I_C = 0$	-5			V
I_{CBO}	Collector Cut-off Current	$V_{CB} = -60V, I_E = 0$			-0.1	μA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = -5V, I_C = 0$			-0.1	μA
h_{FE}	DC Current Gain	$V_{CE} = -6V, I_C = -1mA$	40		700	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -100mA, I_B = -10mA$		-0.18	-0.3	V
$V_{BE(on)}$	Base-Emitter On Voltage	$V_{CE} = -6V, I_E = -1mA$	-0.50	-0.62	-0.80	V
f_T	Current Gain Bandwidth Product	$V_{CE} = -6V, I_C = -10mA$	50	180		MHz
C_{ob}	Output Capacitance	$V_{CB} = -10V, I_E = 0, f = 1MHz$		2.8		pF
NF	Noise Figure	$V_{CE} = -6V, I_C = -0.3mA, f = 100Hz, R_G = 10K\Omega$		6.0	20	dB

h_{FE} Classification

Classification	R	O	Y	G	L
h_{FE}	40 ~ 80	70 ~ 140	120 ~ 240	200 ~ 400	350 ~ 700

Typical Characteristics

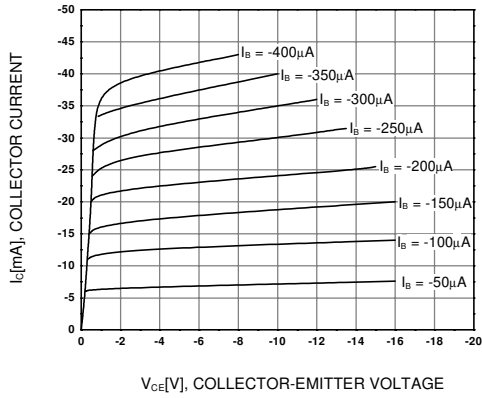


Figure 1. Static Characteristic

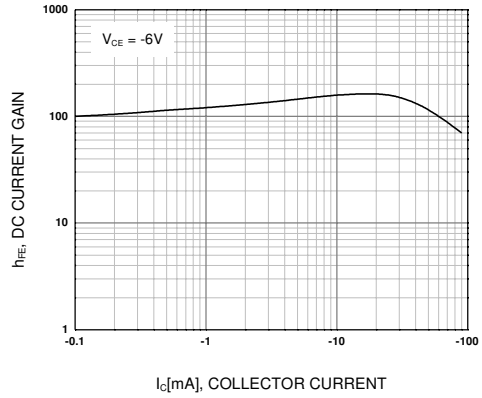
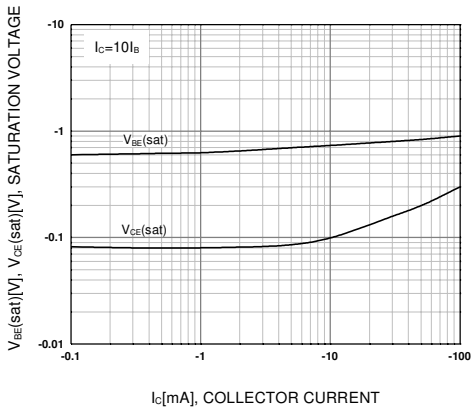


Figure 2. DC current Gain



**Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage**

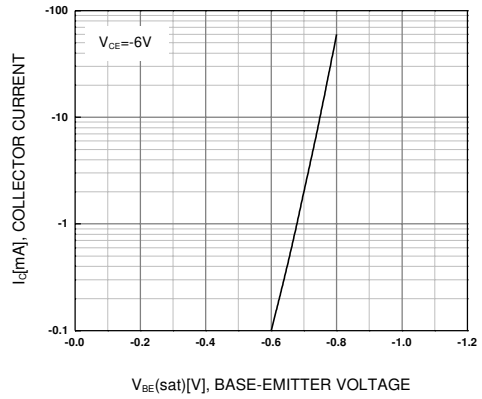


Figure 4. Base-Emitter On Voltage

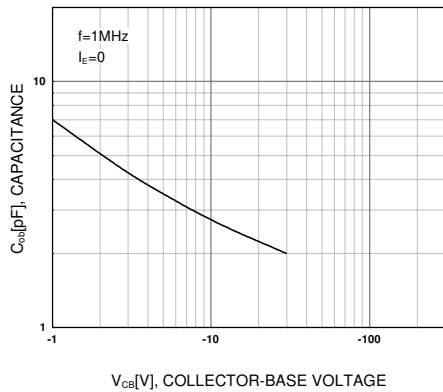


Figure 5. Collector Output Capacitance

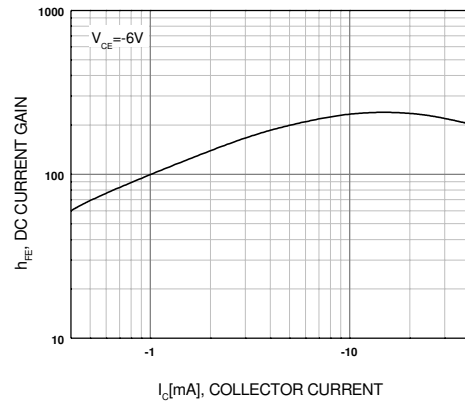
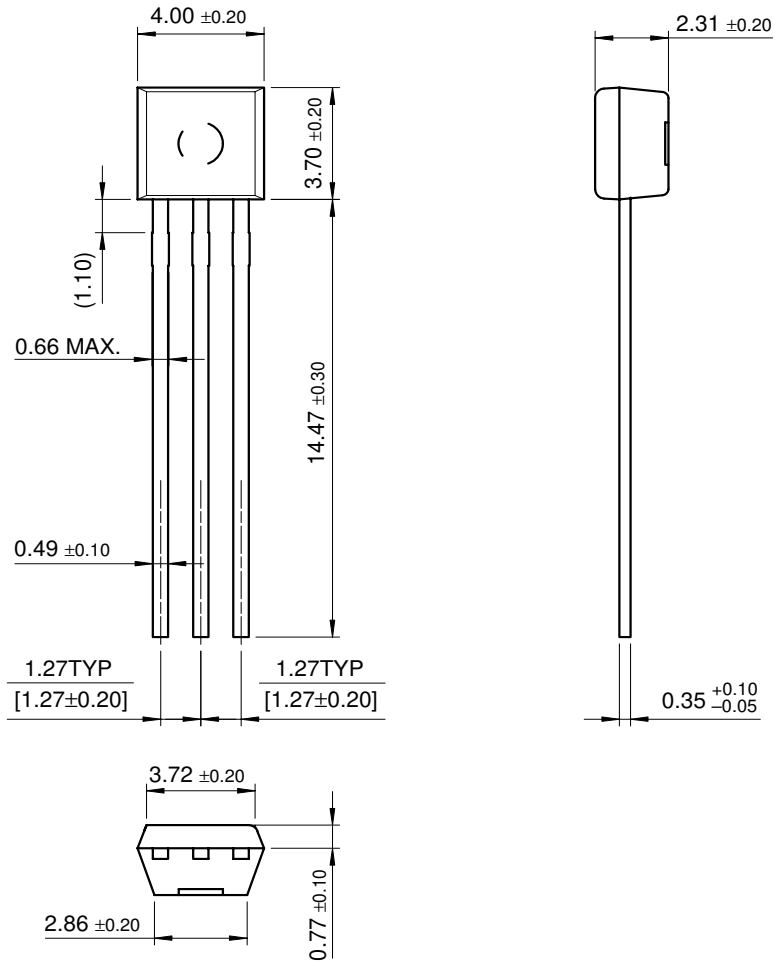


Figure 6. Current Gain Bandwidth Product

Package Dimensions

TO-92S



Dimensions in Millimeters

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CROSSVOL™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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